## UNISONIC TECHNOLOGIES CO., LTD

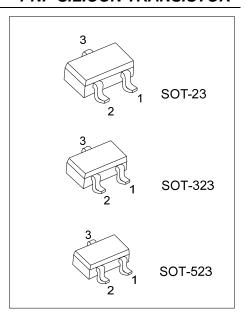
## **DTA114T**

#### PNP SILICON TRANSISTOR

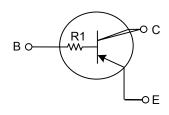
# DIGITAL TRANSISTORS (BUILT- IN BIAS RESISTORS)

#### **■** FEATURES

- \* Built-in bias resistors that implies easy ON/OFF applications.
- \* The bias resistors are thin-film resistors with complete isolation to allow positive input.

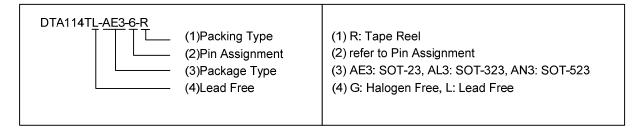


#### **■ EQUIVALENT CIRCUIT**

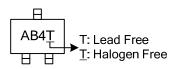


#### ■ ORDERING INFORMATION

Order Number		Dookogo	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
DTA114TL-AE3-6-R	DTA114TG-AE3-6-R	SOT-23	Е	В	О	Tape Reel	
DTA114TL-AL3-6-R	DTA114TG-AL3-6-R	SOT-323	Е	В	O	Tape Reel	
DTA114TL-AN3-6-R	DTA114TG-AN3-6-R	SOT-523	Е	В	С	Tape Reel	



#### MARKING



### ■ ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25°C)

PARAMETER		SYMBOL	RATING	UNIT	
Collector-Base Voltage		$V_{CBO}$	-50	V	
Collector-Emitter Voltage		$V_{\sf CEO}$	-50	V	
Emitter-Base Voltage		$V_{EBO}$	-5	V	
Collector Current		Ic	-100	mA	
Collector Power Dissipation	SOT-23	0	200	mW	
	SOT-323/SOT-523	Pc	150		
Junction Temperature		TJ	+150	$^{\circ}\!\mathbb{C}$	
Storage Temperature		T <sub>STG</sub>	-55~+150	$^{\circ}\!\mathbb{C}$	

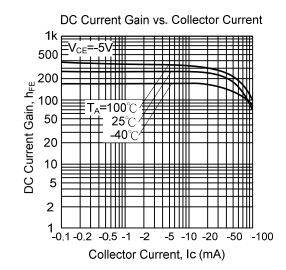
Note Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

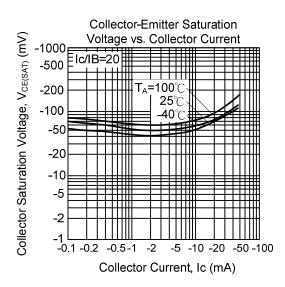
#### ■ ELECTRICAL CHARACTERISTICS (T<sub>A</sub>= 25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Base Breakdown Voltage	$BV_CBO$	I <sub>C</sub> =-50μA	-50			V
Collector-Emitter Breakdown Voltage	$BV_CEO$	I <sub>C</sub> =-1mA	-50			V
Emitter-Base Breakdown Voltage	$BV_{EBO}$	I <sub>E</sub> =-50μA	-5			V
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	I <sub>C</sub> =-10mA, I <sub>B</sub> =-1mA			-0.3	V
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =-50V			-0.5	μΑ
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =-4V			-0.5	μΑ
DC Current Gain	h <sub>FE</sub>	$V_{CE}$ =-5V, $I_{C}$ =-1mA	100	250	600	
Input Resistance	R <sub>1</sub>		7	10	13	kΩ
Transition Frequency	$f_{T}$	V <sub>CE</sub> =-10V, I <sub>E</sub> =5mA,f=100MHz (Note)		250		MHz

Note: Transition frequency of the device

#### **■ TYPICAL CHARACTERISTICS**





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